SLLS213A - JANUARY 1996 - REVISED JUNE 1999

- Single Chip With Easy Interface Between **UART and Serial-Port Connector of an External Modem or Other Computer** Peripheral
- **Five Drivers and Three Receivers Meet or Exceed the Requirements of ANSI Standard** TIA/EIA-232-F and ITU Recommendation V.28 Standards
- Supports Data Rates up to 120 kbit/s
- Complement to the GD75232
- Provides Pin-to-Pin Replacement for the Goldstar GD75323
- **Pin-Out Compatible With SN75196**
- **Functional Replacement for the MC145405**

DW OR N PACKAGE (TOP VIEW) V_{CC} l 20 🛮 V_{DD} 1DA **∏** 2 19 1DY 2DA **∏** 3 18 2DY 3DA **∏** 4 17 **∏** 3DY 1RY **[**] 5 2RY [6 15 2RA 4DA **∏** 7 14**∏** 4DY 13 T 3RA 3RY [8 5DA **∏** 9 12 5DY GND **1** 10 11 [] V_{SS}

description

The GD75323 combines five drivers and three receivers from the trade-standard SN75188 and SN75189 bipolar quadruple drivers and receivers, respectively. The flow-through design of the GD75323 decreases the part count, reduces the board space required, and allows easy interconnection of the UART and serial-port connector. The all-bipolar circuits and processing of the GD75323 provide a rugged, low-cost solution for this function.

The GD75323 complies with the requirements of the ANSI TIA/EIA-232-F and ITU (formerly CCITT) V.28 standards. These standards are for data interchange between a host computer and a peripheral at signal rates up to 20 kbit/s. The switching speeds of the GD75323 are fast enough to support rates up to 120 kbit/s with lower capacitive loads (shorter cables). Interoperability at the higher signaling rates cannot be assured unless the designer has design control of the cable and the interface circuits at both ends. For interoperability at signaling rates up to 120 kbit/s, use of ANSI Standard TIA/EIA-423-B and TIA/EIA-422-B and ITU Recommendations V.10 and V.11 are recommended.

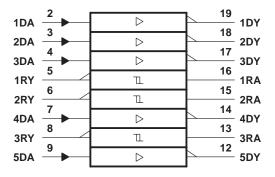
The GD75323 is characterized for operation over a temperature range of 0°C to 70°C.



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



logic symbol†

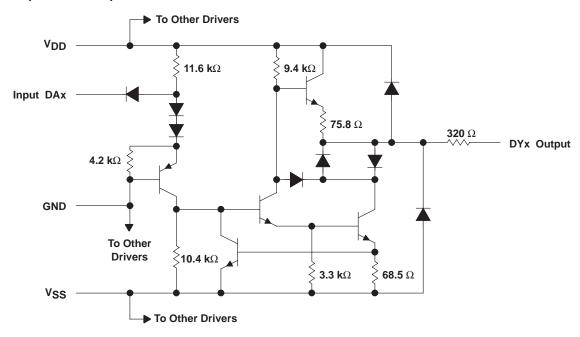


[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)

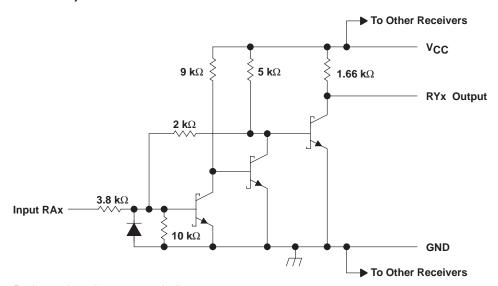


schematic (each driver)



Resistor values shown are nominal.

schematic (each receiver)



Resistor values shown are nominal.

SLLS213A - JANUARY 1996 - REVISED JUNE 1999

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V _{CC} (see Note 1)	10 V
Supply voltage, V _{DD} (see Note 1)	15 V
Supply voltage, VSS (see Note 1)	15 V
Input voltage range, V _I : Driver	
Receiver	30 V to 30 V
Output voltage range, VO (Driver)	– 15 V to 15 V
Low-level output current, IOL (Receiver)	20 mA
Package thermal impedance, θ_{JA} (see Note 2):	DW package
	N package 67°C/W
Lead temperature 1,6 mm (1/16 inch) from case	for 10 seconds
Storage temperature range, T _{sto}	– 65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

recommended operating conditions

		MIN	NOM	MAX	UNIT
	V_{DD}	7.5	9	13.5	
Supply voltage	V _{SS}	-7.5	-9	-13.5	V
	Vcc	4.5	5	5.5	
High-level input voltage, VIH	Driver	1.9			V
Low-level input voltage, V _{IL}	Driver			0.8	V
High level output ourrent leve	Driver			-6	mA
High-level output current, IOH	Receiver			-0.5	ША
High lovel output ourrent les	Driver			6	mA
High-level output current, IOL	Receiver			16	IIIA
Operating free-air temperature,TA		0		70	°C

supply currents over operating free-air temperature range

	PARAMETER		TEST CONDIT	TIONS		MIN	MAX	UNIT
		All inputs at 1.9 V,	No load	$V_{DD} = 9 V$,	$V_{SS} = -9 V$		25	mA
,	Supply current from VDD	All inputs at 1.9 v,	No load	V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$		32	IIIA
I _{DD} Sur	Supply current from VDD	All inputs at 0.8 V,	No load	V _{DD} = 9 V,	$V_{SS} = -9 V$		7.5	mA
			No loau	V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$		9.5	IIIA
	Owner has a surround for any M	~	No load	$V_{DD} = 9 V$,	$V_{SS} = -9 V$		-25	mA
las				V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$		-32	IIIA
ISS	Supply current from VSS		No load	$V_{DD} = 9 V$,	V _{SS} = -9 V		-5.3	m A
		All inputs at 0.8 V,	NO IOAU	V _{DD} = 12 V,	$V_{SS} = -12 \text{ V}$		-5.3	mA
ICC	Supply current from V _{CC}	V _{CC} = 5 V,	All inputs at 5 V,	No load			20	mA



NOTES: 1. All voltages are with respect to the network ground terminal.

^{2.} The package thermal impedance is calculated in accordance with JESD 51, except for through-hole packages, which use a trace length of zero.

DRIVER SECTION

electrical characteristics over operating free-air temperature range, V_{DD} = 9 V, V_{SS} = -9 V, V_{CC} = 5 V (unless otherwise noted)

	PARAMETER		TEST CONDITIO	ONS	MIN	TYP	MAX	UNIT
Vон	High-level output voltage	V _{IL} = 0.8 V,	$R_L = 3 k\Omega$,	See Figure 1	6	7.5		V
V _{OL}	Low-level output voltage (see Note 3)	V _{IH} = 1.9 V,	$R_L = 3 k\Omega$,	See Figure 1		-7.5	-6	V
lн	High-level input current	V _I = 5 V,	See Figure 2				10	μΑ
Ι _Ι L	Low-level input current	V _I = 0,	See Figure 2				-1.6	mA
IOS(H)	High-level short-circuit output current (see Note 4)	V _{IL} = 0.8 V,	V _O = 0,	See Figure 1	-4.5	-9	-19.5	mA
IOS(L)	Low-level short-circuit output current	V _{IH} = 2 V,	$V_{O} = 0$,	See Figure 1	4.5	9	19	mA
ro	r _O Output resistance (see Note 5)		$V_{SS} = 0$,	$V_0 = -2 \text{ V to } 2 \text{ V}$	300			Ω

- NOTES: 3. The algebraic convention, where the more positive (less negative) limit is designated as maximum, is used in this data sheet for logic levels only, e.g., if –10 V is maximum, the typical value is a more negative voltage.
 - 4. Output short-circuit conditions must maintain the total power dissipation below absolute maximum ratings.
 - 5. Test conditions are those specified by TIA/EIA-232-F and as listed above.

switching characteristics, V_{DD} = 12 V, V_{SS} = -12 V, V_{CC} = 5 V $\pm 10\%$, T_A = 25°C

	PARAMETER	TEST CONDITI	ONS	MIN	TYP	MAX	UNIT
^t PLH	Propagation delay time, low- to high-level output	$R_L = 3 \text{ k}\Omega \text{ to } 7 \text{ k}\Omega,$	C _L = 15 pF,		315	500	ns
t _{PHL}	Propagation delay time, high- to low-level output	See Figure 3			75	175	ns
	Transition time, low- to high-level output	R_L = 3 kΩ to 7 kΩ, See Figure 3	C _L = 15 pF,		60	100	ns
^t TLH		R_L = 3 kΩ to 7 kΩ, See Figure 3 and Note 6	$C_L = 2500 \text{ pF},$		1.7	2.5	μs
<u></u>	Transition time, high- to low-level output (see Note 5)	R_L = 3 kΩ to 7 kΩ, See Figure 3	C _L = 15 pF,		40	75	ns
[†] THL		R_L = 3 kΩ to 7 kΩ, See Figure 3 and Note 7	$C_L = 2500 \text{ pF},$		1.5	2.5	μs

- NOTES: 6. Measured between 3-V and 3-V points of the output waveform (TIA/EIA-232-F conditions), all unused inputs are tied either high or low.
 - 7. Measured between 3-V and -3-V points of the output waveform (TIA/EIA-232-F conditions), all unused inputs are tied either high or low.



RECEIVER SECTION

electrical characteristics over recommended operating conditions (unless otherwise noted)

	PARAMETER	TEST C	ONDITIONS	MIN	TYP [†]	MAX	UNIT	
\/	Positive-going input threshold voltage	See Figure 5	T _A = 25°C	1.75	1.9	2.3		
VIT+	Fositive-going input tilleshold voltage	See Figure 5	$T_A = 0$ °C to 70 °C	1.55		2.3	V	
V _{IT} _	Negative-going input threshold voltage	See Figure 5		0.75	0.97	1.25	V	
V _{hys}	Input hysteresis voltage (V _{IT+} – V _{IT-})	See Figure 5		0.5				
V0	High-level output voltage	I _{OH} = -0.5 mA	V _{IH} = 0.75 V	2.6	4	5	V	
VOH	r light-level output voltage	10H = -0.5 IIIA	Inputs open	2.6			V	
VOL	Low-level output voltage	$I_{OL} = 10 \text{ mA},$	V _I = 3 V		0.2	0.45	V	
1	High-level input current	V _I = 25 V,	See Figure 5	3.6		8.3	mA	
I'IH	riigir-ieveriiiput current	V _I = 3 V,	See Figure 5	0.43			IIIA	
1	Low-level input current	$V_{I} = -25 \text{ V},$	See Figure 5	-3.6		-8.3	mA	
¹ ∟	Low-level input current	$V_{I} = -3 V$,	See Figure 5	-0.43			IIIA	
los	Short-circuit output current	See Figure 4			-3.4	-12	mA	

[†] All typical values are at $T_A = 25^{\circ}C$, $V_{CC} = 5$ V, $V_{DD} = 9$ V, and $V_{SS} = -9$ V.

switching characteristics, V_{CC} = 5 V, V_{DD} = 12 V, V_{SS} = -12 V, T_A = 25°C

	PARAMETER	TEST CO	NDITIONS	MIN	TYP	MAX	UNIT
tPLH	Propagation delay time, low- to high-level output				107	500	ns
tPHL	Propagation delay time, high- to low-level output	$C_L = 50 \text{ pF},$	$R_L = 5 k\Omega$,		42	150	ns
^t TLH	Transition time, low- to high-level output	See Figure 6			175	525	ns
tTHL	Transition time, high- to low-level output				16	60	ns

PARAMETER MEASUREMENT INFORMATION

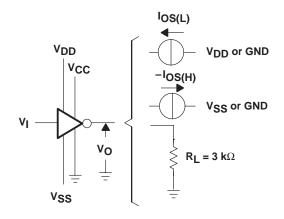


Figure 1. Driver Test Circuit for V_{OH} , V_{OL} , $I_{OS(H)}$, and $I_{OS(L)}$

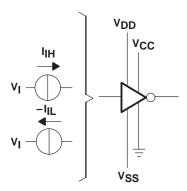
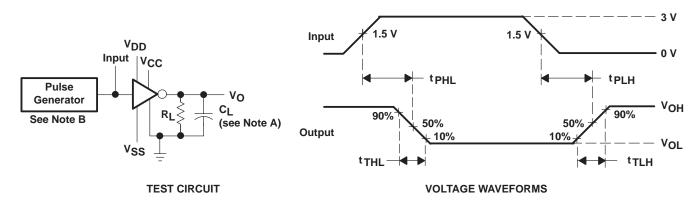


Figure 2. Driver Test Circuit for $I_{\mbox{\scriptsize IH}}$ and $I_{\mbox{\scriptsize IL}}$



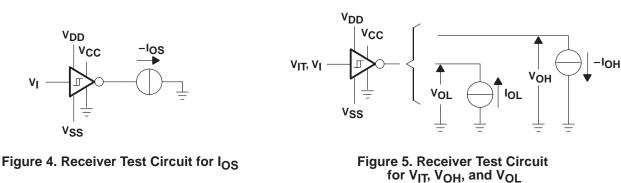
PARAMETER MEASUREMENT INFORMATION



NOTES: A. C_I includes probe and jig capacitance.

B. The pulse generator has the following characteristics: t_W = 25 μ s, PRR = 20 kHz, Z_O = 50 Ω , t_r = t_f < 50 ns.

Figure 3. Driver Test Circuit and Voltage Waveforms



50% 50% Input -5 V ^tPHL ^tPLH Vон 90% 50% 50% Output 10% 10% Vol tTHLtTLH

VOLTAGE WAVEFORMS

Input **Pulse** ۷o Generator See Note B (see Note A) VSS

NOTES: A. C_I includes probe and jig capacitance.

TEST CIRCUIT

 V_{DD}

B. The pulse generator has the following characteristics: $t_W = 25 \,\mu s$, PRR = 20 kHz, $Z_O = 50 \,\Omega$, $t_T = t_f < 50 \,ns$.

Figure 6. Receiver Propagation and Transition Times

TYPICAL CHARACTERISTICS DRIVER SECTION

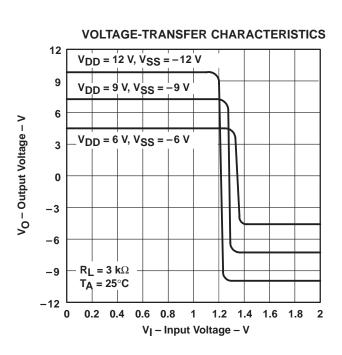
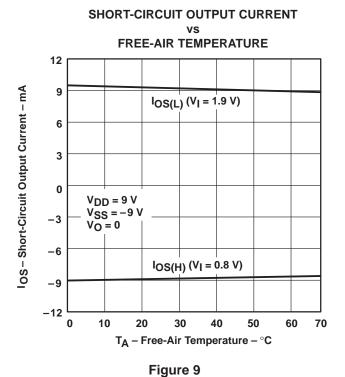
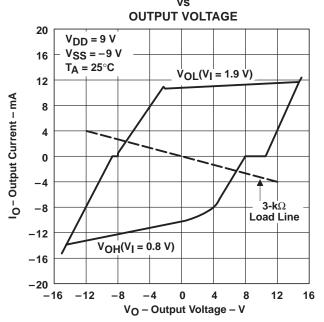


Figure 7





OUTPUT CURRENT

Figure 8

SLEW RATE vs LOAD CAPACITANCE

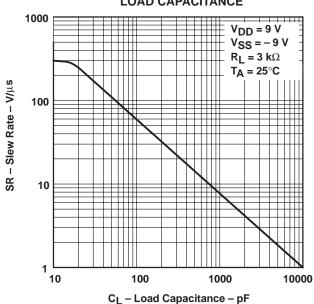


Figure 10



TYPICAL CHARACTERISTICS **RECEIVER SECTION**

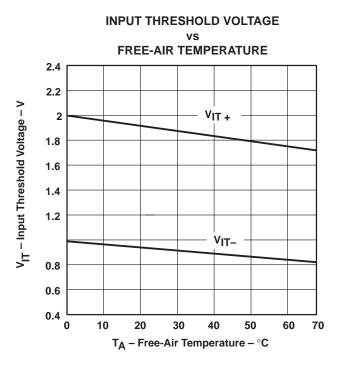
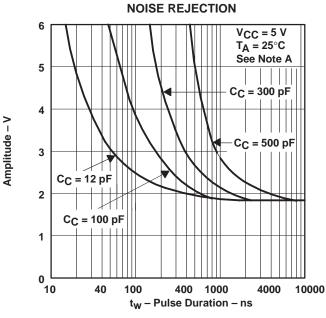


Figure 11



NOTE A: This figure shows the maximum amplitude of a positive-going pulse that, starting from 0 V, does not cause a change of the output level.

Figure 13

INPUT THRESHOLD VOLTAGE SUPPLY VOLTAGE 2 $V_{\text{IT+}}$ 1.8 V_{IT} - Input Threshold Voltage - V 1.6 1.4 1.2 1 V_{IT}-0.8 0.6 0.4 0.2 0 2 3 5 8 9 10 V_{CC} - Supply Voltage - V

Figure 12

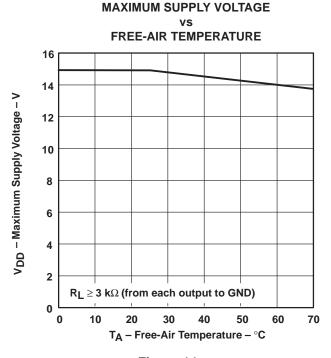


Figure 14



APPLICATION INFORMATION

Diodes placed in series with the V_{DD} and V_{SS} leads protect the GD75323 in the fault condition in which the device outputs are shorted to V_{DD} or V_{SS} , and the power supplies are at low and provide low-impedance paths to ground (see Figure 15).

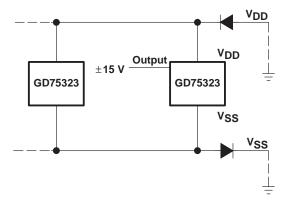
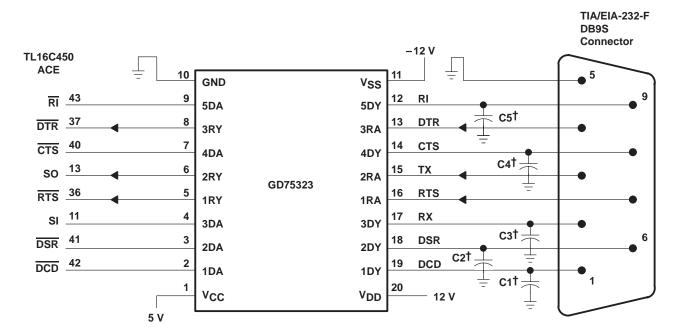


Figure 15. Power-Supply Protection to Meet Power-Off Fault Conditions of TIA/EIA-232-F



[†] See Figure 10 to select the correct values for the loading capacitors (C1, C2, C3, C4, and C5), which may be required to meet the RS-232 maximum slew-rate requirement of 30 V/μs. The value of the loading capacitors required depends upon the line length and desired slew rate, but is typically 330 pF.

NOTE C: To use the receivers only, VDD and VSS both must be powered or tied to ground.

Figure 16. Typical Connection







www.ti.com 24-Jan-2013

PACKAGING INFORMATION

Orderable Device	Status	Package Type	-		Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing			(2)		(3)		(4)	
GD75323DW	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323	Samples
GD75323DWE4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323	Samples
GD75323DWG4	ACTIVE	SOIC	DW	20	25	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323	Samples
GD75323DWR	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323	Samples
GD75323DWRE4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323	Samples
GD75323DWRG4	ACTIVE	SOIC	DW	20	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM	0 to 70	GD75323	Samples
GD75323N	OBSOLETE	PDIP	N	20		TBD	Call TI	Call TI	0 to 70		

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): Tl's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

⁽³⁾ MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

⁽⁴⁾ Only one of markings shown within the brackets will appear on the physical device.



PACKAGE OPTION ADDENDUM

24-Jan-2013

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 26-Jan-2013

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
GD75323DWR	SOIC	DW	20	2000	330.0	24.4	10.8	13.0	2.7	12.0	24.0	Q1

www.ti.com 26-Jan-2013



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
GD75323DWR	SOIC	DW	20	2000	367.0	367.0	45.0

N (R-PDIP-T**)

PLASTIC DUAL-IN-LINE PACKAGE

16 PINS SHOWN



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Falls within JEDEC MS-001, except 18 and 20 pin minimum body length (Dim A).
- The 20 pin end lead shoulder width is a vendor option, either half or full width.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



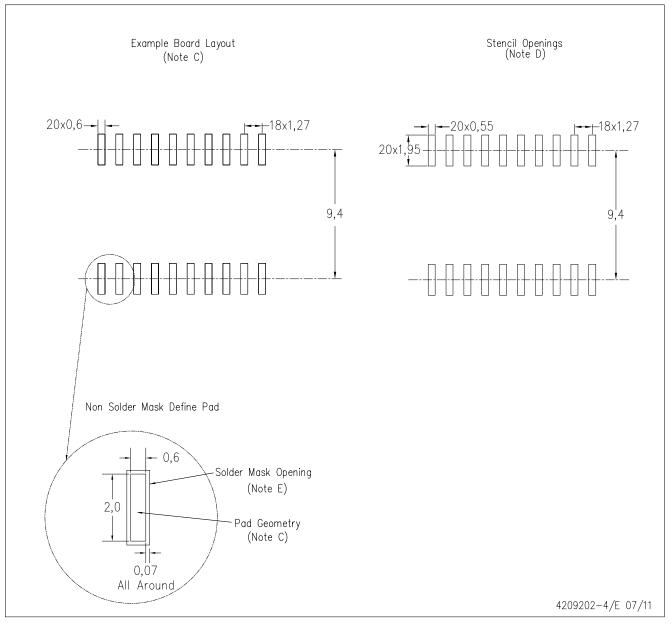
NOTES: A. All linear dimensions are in inches (millimeters). Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013 variation AC.



DW (R-PDSO-G20)

PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Refer to IPC7351 for alternate board design.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC—7525
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>